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## TRANSMITTAL OF FORMAL DRAWINGS

Docket No.

SLA0803

In Re Application Of: Sheng Teng Hsu, Wei Pan, Fengyan Zhang, Wei-Wei Zhuang and Tingkai Li

Serial No.

10/730,584

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Examiner

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Art Unit

2826

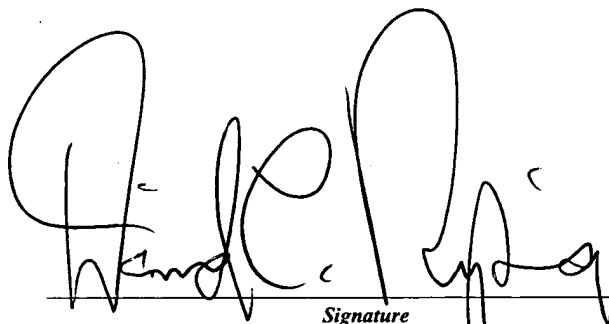
Invention: RRAM Memory Cell Electrodes

Address to:

Assistant Commissioner for Patents  
Washington, D.C. 20231

Transmitted herewith are:

2 sheets of formal drawing(s) for this application.

Each sheet of drawing indicates the identifying indicia suggested in 37 CFR Section 1.84(c)  
on the reverse side of the drawing.

Signature

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Dated: November 4, 2004

I certify that this document and attached formal drawings  
are being deposited on November 4 2004 with the  
U.S. Postal Service as first class mail under 37 C.F.R. 1.8  
and addressed to the Assistant Commissioner for Patents,  
Washington, D.C. 20231.

Signature of Person Mailing Correspondence

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